



60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

25 A

Features

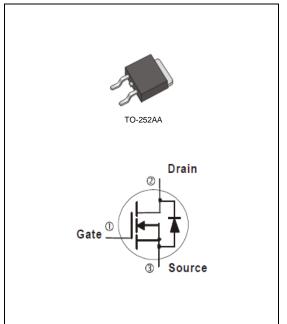
- $R_{DS(ON)}$, $V_{GS}@10V$, I_{D} $\overline{@15A<34m\Omega}$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@10A<40m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-252AA Package

Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|-----------------------|-------------------|-------------|-------|--|
| Drain-Source Voltage | | V_{DS} | 60 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current | T _C =25°C | I _D | 25 | A | |
| | T _C =100°C | | 16 | | |
| Pulsed Drain Current(Note 1) | T _C =25°C | I _{DM} | 100 | | |
| Power Dissipation | T _C =25°C | Po | 48.4 | W | |
| | T _C =100°C | | 24.2 | | |
| Continuous Drain Current | T _A =25°C | I _D | 5.5 | А | |
| | T _A =70°C | | 4.4 | А | |
| Power Dissipation | T _A =25°C | 1 | 2.4 | W | |
| Power Dissipation | T _A =70°C | Pb | 1.6 | | |
| Single Pulse Avalanche Energy (Note 6) | | E _{AS} | 24 | mJ | |
| Operating Junction and Storage Temperature Range | | T_J , T_{STG} | -55~175 | °C | |
| Typical Thermal resistance ^(Note 4,5) | Junction to Case | $R_{	heta JC}$ | 3.1 | °C/W | |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | | |

Limited only By Maximum Junction Temperature





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | | |
|----------------------------------|---------------------|--|------|------|--------------|-------|--|--|
| Static | | | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V _{GS} =0V,I _D =250uA | 60 | - | - | V | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=250uA$ | 1.0 | 1.83 | 2.5 | V | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V,I _D =15A | - | 28 | 34 | mΩ | | |
| | | V _{GS} =4.5V,I _D =10A | | 33 | 40 | | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =60V, V_{GS} =0V | - | - | 1.0 | uA | | |
| Gate-Source Leakage Current | I_{GSS} | $V_{GS}=\underline{+}20V, V_{DS}=0V$ | - | - | <u>+</u> 100 | nA | | |
| Dynamic (Note 7) | | | | | | | | |
| Total Gate Charge | Q_{g} | V _{DS} =30V, I _D =20A, V _{GS} =10V ^(Note 1,2) | - | 20 | - | nC | | |
| Gate-Source Charge | Q_gs | | - | 3.8 | - | | | |
| Gate-Drain Charge | Q_{gd} | | - | 3.9 | - | | | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1.0MHZ | - | 1173 | - | pF | | |
| Output Capacitance | Coss | | - | 63 | - | | | |
| Reverse Transfer Capacitance | Crss | I=1.0IVIMZ | - | 44 | - | | | |
| Turn-On Delay Time | td _(on) | \/ 45\/ 45 | - | 7.1 | - | ns | | |
| Turn-On Rise Time | t _r | V_{DD} =15V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 1,2) | - | 25 | - | | | |
| Turn-Off Delay Time | td _(off) | | - | 31 | - | | | |
| Turn-Off Fall Time | t _f | | - | 20 | - | | | |
| Drain-Source Diode | | | | | | | | |
| Maximum Continuous Drain-Source | | | | | 25 | Λ . | | |
| Diode Forward Current | I _S | | - | - | 25 | Α | | |
| Diode Forward Voltage | V_{SD} | I _S =1A,V _{GS} =0V | - | 0.72 | 1.2 | V | | |

NOTES:

- 1. Pulse width<a>300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I_{AS} =22A, V_{DD} =25V, V_{GS} =10V
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

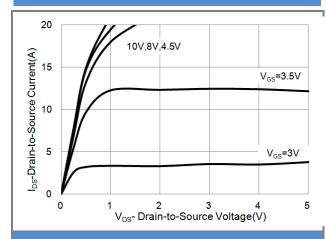


Fig.1 Output Characteristics

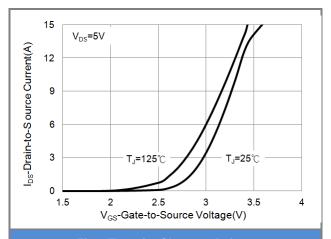


Fig.2 Transfer Characteristics

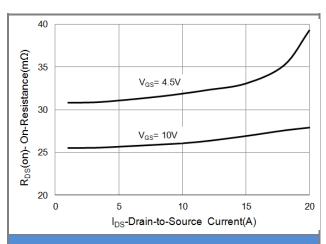


Fig.3 On-Resistance vs. Drain Current

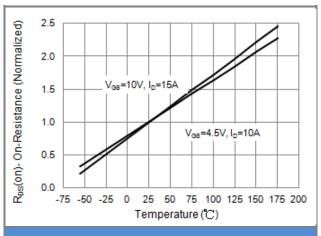


Fig.4 On-Resistance vs. Junction temperature

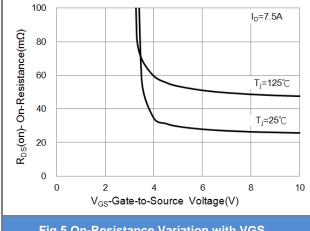


Fig.5 On-Resistance Variation with VGS.

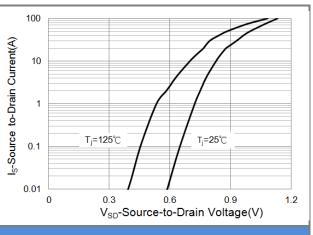


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

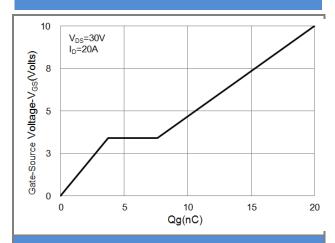


Fig.7 Gate-Charge Characteristics

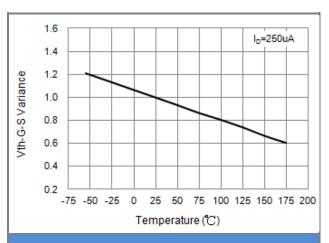


Fig.9 Threshold Voltage Variation with Temperature

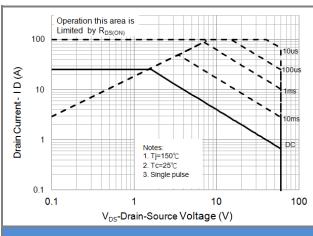


Fig.11 Maximum Safe Operating Area

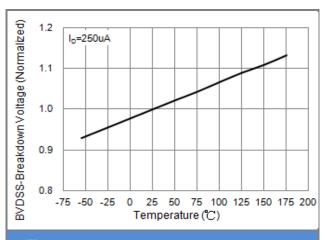


Fig.8 Breakdown Voltage Variation vs. Temperature

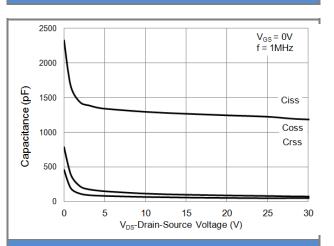


Fig.10 Capacitance vs. Drain-Source Voltage





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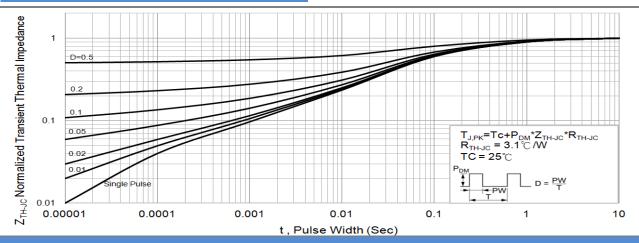


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

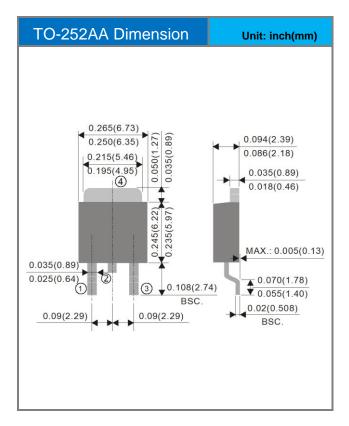


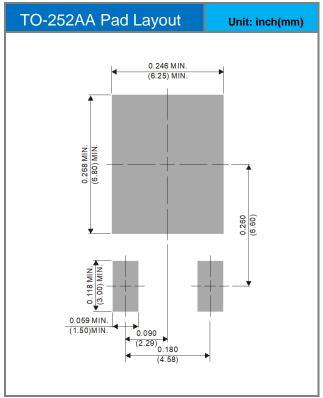


PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing Type | Marking | Version | |
|-----------------------|--------------|---------------------|---------|--------------|--|
| PJD25N06A-AU_L2_000A1 | TO-252AA | 3,000pcs / 13" reel | D25N06A | Halogen free | |

Packaging Information & Mounting Pad Layout









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